

N-channel 60 V, 3.9 mΩ standard level MOSFET in SOT78 1 February 2013 Product data sheet

### 1. General description

Standard level N-channel MOSFET in SOT78 using TrenchMOS technology. Product design and manufacture has been optimized for use in battery operated power tools.

### 2. Features and benefits

- High efficiency due to low switching & conduction losses
- Robust construction for demanding applications
- Standard level gate

### 3. Applications

- Battery-powered tools
- Load switching
- Motor control
- Uninterruptible power supplies

### 4. Quick reference data

Table 1. Qui	ick reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> ≥ 25 °C; T <sub>j</sub> ≤ 175 °C		-	-	60	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 25 °C; <u>Fig. 1</u>	[1]	-	-	130	А
P <sub>tot</sub>	total power dissipation	T <sub>mb</sub> = 25 °C; <u>Fig. 2</u>		-	-	263	W
Static charact	teristics						,
R <sub>DSon</sub>	drain-source on-state resistance	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 25 A; T <sub>j</sub> = 25 °C; Fig. 11		-	2.94	3.9	mΩ
Dynamic chai	acteristics	·					
Q <sub>G(tot)</sub>	total gate charge	$I_D$ = 25 A; $V_{DS}$ = 48 V; $V_{GS}$ = 10 V;		-	103	-	nC
Q <sub>GD</sub>	gate-drain charge	<u>Fig. 13; Fig. 14</u>		-	33	-	nC
Avalanche rug	ggedness				1		
E <sub>DS(AL)S</sub>	non-repetitive drain- source avalanche energy	$I_D$ = 130 A; $V_{sup} \le 60$ V; $R_{GS}$ = 50 Ω; $V_{GS}$ = 10 V; $T_{j(init)}$ = 25 °C; unclamped; Fig. 3		-	-	283	mJ

[1] Continuous current is limited by package.

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### 5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	mb	D
2	D	drain	$2 \sim 10$	
3	S	source		G L F A
mb	D	mounting base; connected to drain		mbb076 S
			TO-220AB (SOT78)	

# 6. Ordering information

Table 3. Ordering information							
Type number	Package						
	Name	Description	Version				
PSMN3R9-60PS	TO-220AB	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB	SOT78				

### 7. Marking

Table 4. Marking codes	
Type number	Marking code
PSMN3R9-60PS	PSMN3R9-60PS

# 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

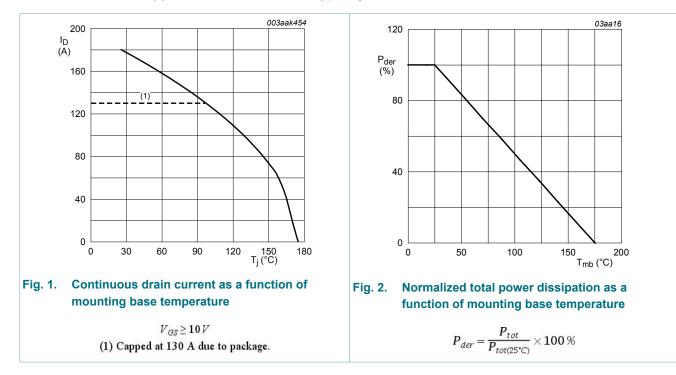
Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>DS</sub>	drain-source voltage	$T_j \ge 25 \text{ °C}; T_j \le 175 \text{ °C}$		-	60	V
V <sub>DGR</sub>	drain-gate voltage	R <sub>GS</sub> = 20 kΩ		-	60	V
V <sub>GS</sub>	gate-source voltage			-20	20	V
I <sub>D</sub>	drain current	T <sub>mb</sub> = 25 °C; V <sub>GS</sub> = 10 V; <u>Fig. 1</u>	[1]	-	130	А
		T <sub>mb</sub> = 100 °C; V <sub>GS</sub> = 10 V; <u>Fig. 1</u>		-	127	А
I <sub>DM</sub>	peak drain current	$T_{mb}$ = 25 °C; pulsed; $t_p \le 10 \ \mu$ s; Fig. 4		-	705	А

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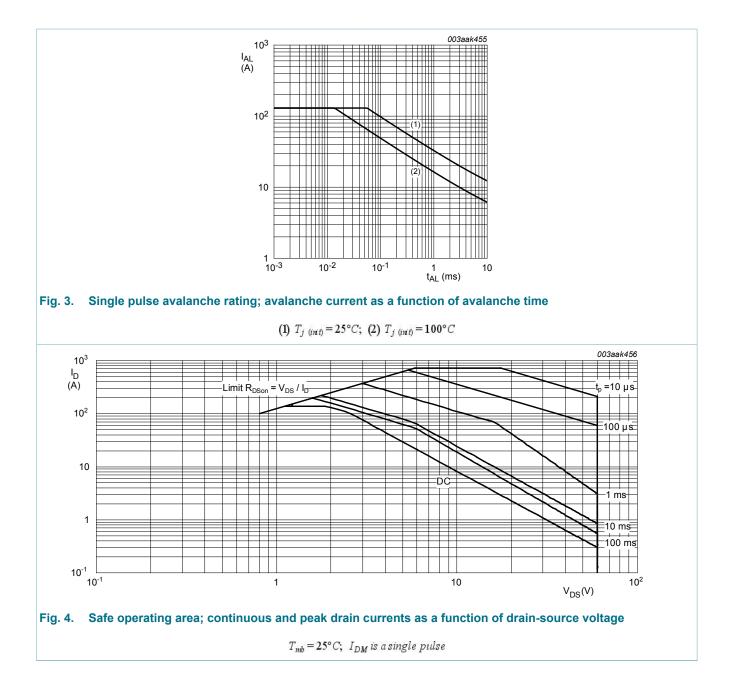
Symbol	Parameter	Conditions		Min	Мах	Unit
P <sub>tot</sub>	total power dissipation	T <sub>mb</sub> = 25 °C; <u>Fig. 2</u>		-	263	W
T <sub>stg</sub>	storage temperature			-55	175	°C
Tj	junction temperature			-55	175	°C
T <sub>sld(M)</sub>	peak soldering temperature			-	260	°C
Source-drai	in diode					
I <sub>S</sub>	source current	T <sub>mb</sub> = 25 °C	[1]	-	130	А
I <sub>SM</sub>	peak source current	pulsed; $t_p \le 10 \ \mu s$ ; $T_{mb} = 25 \ ^{\circ}C$		-	705	А
Avalanche	ruggedness					
E <sub>DS(AL)S</sub>	non-repetitive drain-source avalanche energy	$\begin{split} & I_{D} = 130 \; A;  V_{sup} \leq 60 \; V;  R_{GS} = 50 \; \Omega; \\ & V_{GS} = 10 \; V;  T_{j(init)} = 25 \; ^{\circ}C; \; unclamped; \\ & \overline{Fig. 3} \end{split}$		-	283	mJ



[1] Continuous current is limited by package.

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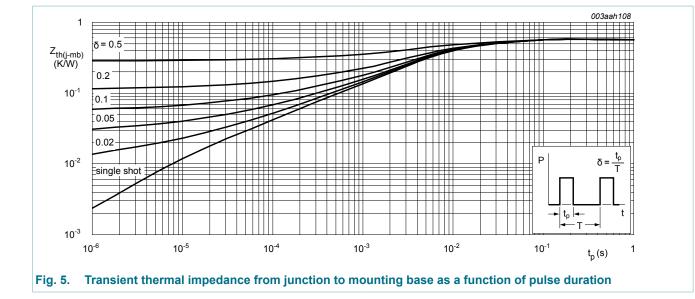
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### 9. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-mb)</sub>	thermal resistance from junction to mounting base	<u>Fig. 5</u>	-	0.49	0.57	K/W
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	vertical in still air	-	60	-	K/W

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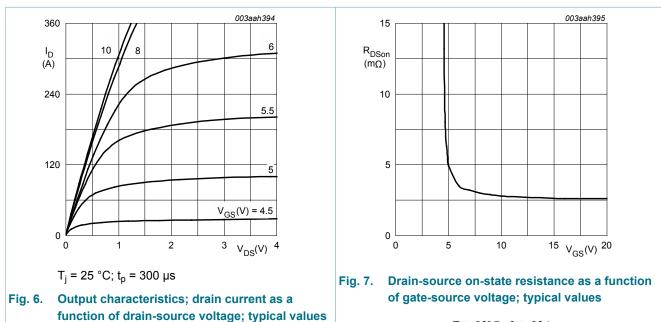
### **10.** Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V <sub>(BR)DSS</sub>	drain-source	$I_D$ = 250 µA; $V_{GS}$ = 0 V; $T_j$ = 25 °C	60	-	-	V
	breakdown voltage	$I_D = 250 \ \mu A; V_{GS} = 0 \ V; T_j = -55 \ ^{\circ}C$	54	-	-	V
V <sub>GS(th)</sub>	gate-source threshold voltage	$I_D$ = 1 mA; $V_{DS}$ = $V_{GS}$ ; $T_j$ = 25 °C; Fig. 9; Fig. 10	2.4	3	4	V
		$I_D$ = 1 mA; $V_{DS}$ = $V_{GS}$ ; $T_j$ = 175 °C; Fig. 9	1	-	-	V
		$I_D$ = 1 mA; $V_{DS}$ = $V_{GS}$ ; $T_j$ = -55 °C; Fig. 9	-	-	4.5	V
I <sub>DSS</sub>	drain leakage current	$V_{DS}$ = 60 V; $V_{GS}$ = 0 V; $T_j$ = 175 °C	-	-	500	μA
		$V_{DS}$ = 60 V; $V_{GS}$ = 0 V; $T_j$ = 25 °C	-	0.07	1	μA
I <sub>GSS</sub>	s gate leakage current	$V_{GS}$ = 20 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C	-	2	100	nA
		$V_{GS}$ = -20 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C	-	2	100	nA
R <sub>DSon</sub>	drain-source on-state resistance	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 25 A; T <sub>j</sub> = 25 °C; Fig. 11	-	2.94	3.9	mΩ
		V <sub>GS</sub> = 10 V; I <sub>D</sub> = 25 A; T <sub>j</sub> = 175 °C; Fig. 11; Fig. 12	-	-	8.5	mΩ
R <sub>G</sub>	gate resistance	f = 1 MHz	0.35	0.7	1.4	Ω
Dynamic cl	naracteristics		I			
Q <sub>G(tot)</sub>	total gate charge	$I_D$ = 25 A; $V_{DS}$ = 48 V; $V_{GS}$ = 10 V;	-	103	-	nC
Q <sub>GS</sub>	gate-source charge	<u>Fig. 13; Fig. 14</u>	-	25.1	-	nC

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Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Q <sub>GD</sub>	gate-drain charge			-	33	-	nC
C <sub>iss</sub>	input capacitance	V <sub>GS</sub> = 0 V; V <sub>DS</sub> = 25 V; f = 1 MHz;		-	5600	-	pF
C <sub>oss</sub>	output capacitance	T <sub>j</sub> = 25 °C; <u>Fig. 15</u>		-	740	-	pF
C <sub>rss</sub>	reverse transfer capacitance			-	460	-	pF
t <sub>d(on)</sub>	turn-on delay time	$V_{DS}$ = 45 V; R <sub>L</sub> = 1.8 Ω; V <sub>GS</sub> = 10 V; R <sub>G(ext)</sub> = 5 Ω		-	25.3	-	ns
t <sub>r</sub>	rise time			-	41.4	-	ns
t <sub>d(off)</sub>	turn-off delay time			-	62.7	-	ns
t <sub>f</sub>	fall time	-		-	45	-	ns
Source-dra	ain diode	l	1				
V <sub>SD</sub>	source-drain voltage	$I_{S}$ = 25 A; $V_{GS}$ = 0 V; $T_{j}$ = 25 °C; <u>Fig. 16</u>		-	0.8	1.2	V
t <sub>rr</sub>	reverse recovery time	$\rm I_S$ = 20 A; dI_S/dt = -100 A/µs; V_{GS} = 0 V; $\rm V_{DS}$ = 25 V		-	39	-	ns
Qr	recovered charge			-	51	-	nC

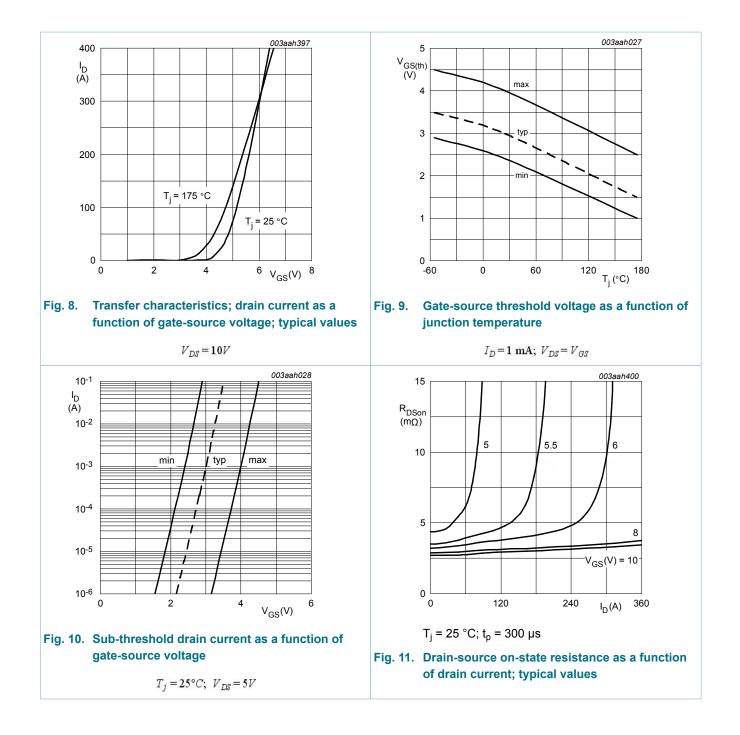


 $T_j = 25^{\circ}C; \ I_D = 25A$ 

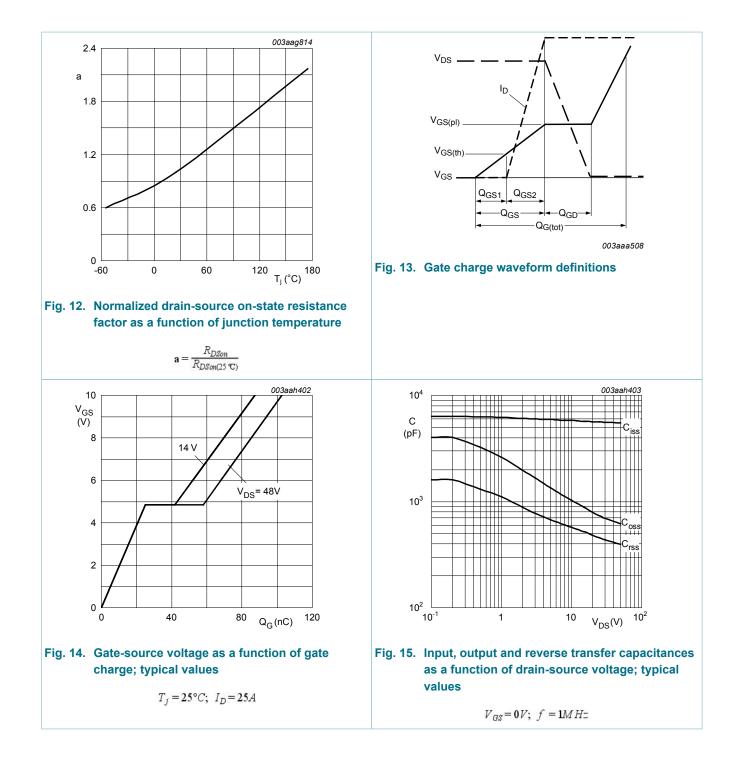
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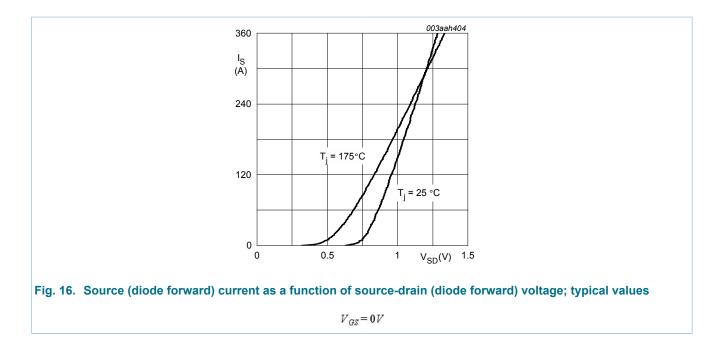


#### N-channel 60 V, 3.9 m $\Omega$ standard level MOSFET in SOT78



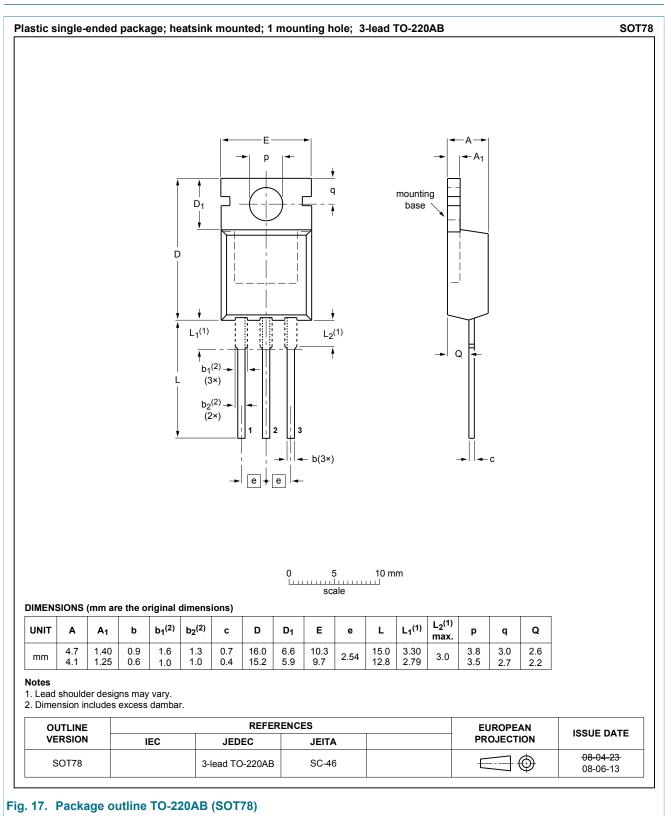
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### 11. Package outline



#### PSMN3R9-60PS

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Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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